

# MOS FIELD EFFECT TRANSISTOR $\mu$ PA1721

### SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

#### DESCRIPTION

The  $\mu$ PA1721 is N-Channel MOS Field Effect Transistor designed for DC/DC converters and power management applications of notebook computers.

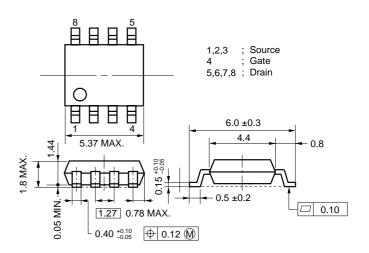
#### FEATURES

- Low on-resistance  $R_{DS(on)1} = 10.5 \text{ m}\Omega \text{ MAX.}$  (Vgs = 10 V, ID = 5.0 A)  $R_{DS(on)2} = 14.0 \text{ m}\Omega \text{ MAX.}$  (Vgs = 4.5 V, ID = 5.0 A)  $R_{DS(on)3} = 17.0 \text{ m}\Omega \text{ MAX.}$  (Vgs = 4.0 V, ID = 5.0 A)
- Low Ciss: Ciss = 2200 pF TYP.
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

#### **ORDERING INFORMATION**

PART NUMBER	PACKAGE
μΡΑ1721G	Power SOP8

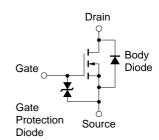
#### PACKAGE DRAWING (Unit : mm)



#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

#### EQUIVALENT CIRCUIT

Drain to Source Voltage (Vgs = 0 V)	VDSS	30	V	
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V	
Drain Current (DC)	D(DC)	±10	А	
Drain Current (pulse) <sup>Note1</sup>	D(pulse)	±40	А	
Total Power Dissipation $(T_A = 25^{\circ}C)^{Note2}$	Р⊤	2.0	W	
Channel Temperature	Tch	150	°C	
Storage Temperature	Tstg	–55 to +150	°C	



**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1 %

2. Mounted on ceramic substrate of 1200 mm<sup>2</sup> x 2.2 mm

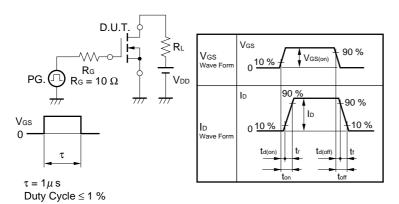
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**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

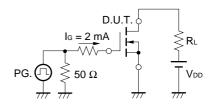
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 5.0 A		8.0	10.5	mΩ
	RDS(on)2	Vgs = 4.5 V, Id = 5.0 A		10.0	14.0	mΩ
	RDS(on)3	Vgs = 4.0 V, Id = 5.0 A		12.0	17.0	mΩ
Gate to Source Cut-off Voltage	VGS(off)	Vds = 10 V, Id = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	y <sub>fs</sub>	Vds = 10 V, Id = 5.0 A	7.0	14.0		S
Drain Leakage Current	IDSS	$V_{DS} = 30 V, V_{GS} = 0 V$			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	VDS = 10 V		2200		pF
Output Capacitance	Coss	Vgs = 0 V		710		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		270		pF
Turn-on Delay Time	td(on)	ID = 5.0 A		30		ns
Rise Time	tr	$V_{GS(on)} = 10 V$		90		ns
Turn-off Delay Time	$t_{d(off)}$	Vdd = 15 V		90		ns
Fall Time	tr	R <sub>G</sub> = 10 Ω		50		ns
Total Gate Charge	Q <sub>G</sub>	ID = 10 A		39		nC
Gate to Source Charge	QGS	Vdd = 24 V		6.3		nC
Gate to Drain Charge	Qgd	V <sub>GS</sub> = 10 V		10.0		nC
Body Diode Forward Voltage	VF(S-D)	IF = 10 A, VGs = 0 V		0.8		V
Reverse Recovery Time	trr	IF = 10 A, VGS = 0 V		40		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ μs		50		nC

#### ELECTRICAL CHARACTERISTICS (TA = 25 °C, All terminals are connected.)

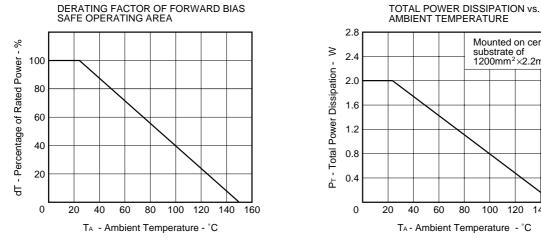
#### TEST CIRCUIT 1 SWITCHING TIME

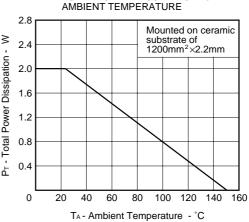


#### TEST CIRCUIT 2 GATE CHARGE

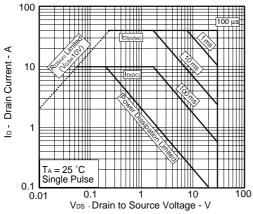


TYPICAL CHARACTERISTICS (TA = 25 °C) \*

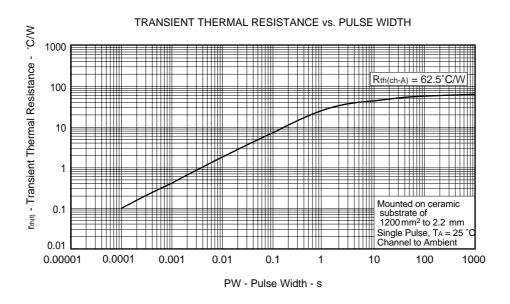






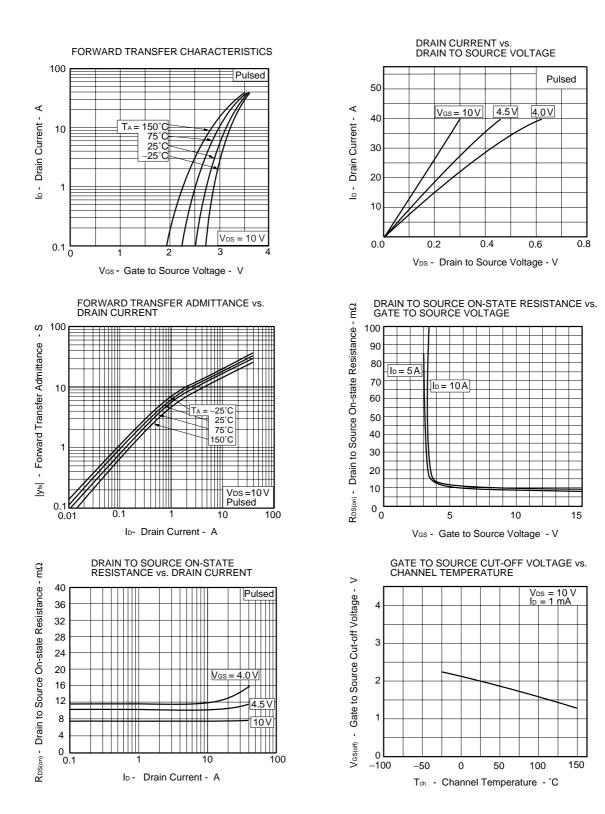


Note Mounted on ceramic substrate of  $1200 \text{ mm}^2 \times 2.2 \text{ mm}$ 



Data Sheet G13889EJ1V0DS00

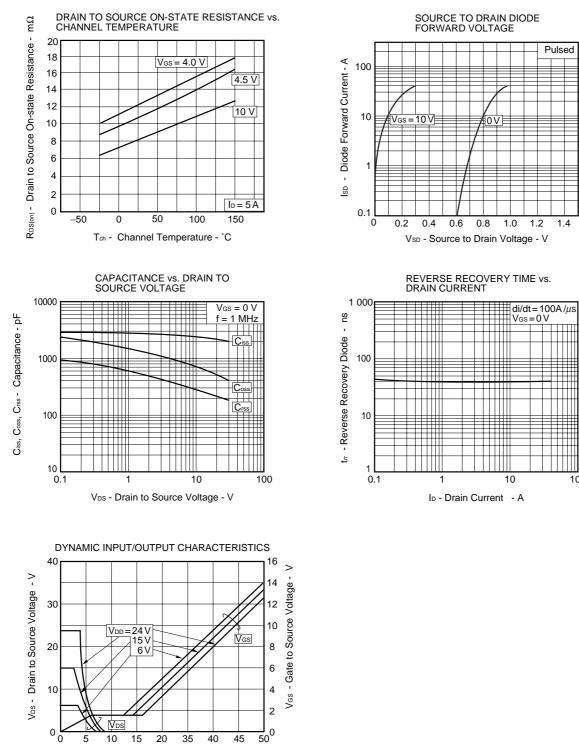




μ**PA1721** 

1.4

100



15 20 35 40 10 QG - Gate Charge - nC

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## NEC

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